FAIRCHILD SEMICONDUCTOR™

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MM74C32
Quad 2-Input OR Gate

General Description

The MM74C32 employs complementary MOS (CMOS) transistors to achieve low power and high noise margin, these gates provide the basic functions used in the implementation of digital integrated circuit systems. The N- and P-channel enhancement mode transistors provide a symmetrical circuit with output swings essentially equal to the supply voltage. This results in high noise immunity over a wide supply voltage range. No DC power other than that caused by leakage current is consumed during static conditions. All inputs are protected against static discharge damage.

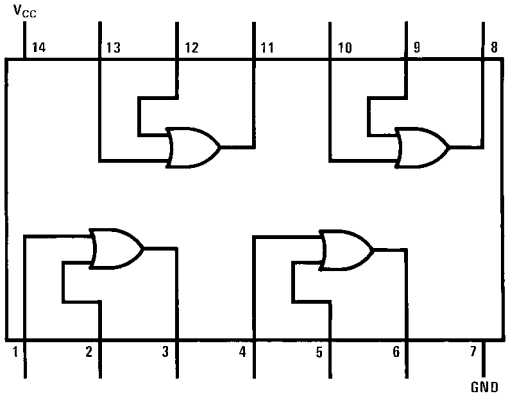
Features

- Wide supply voltage range: 3.0V to 15V
- Guaranteed noise margin: 1.0V
- High noise immunity: 0.45V V_{CC} (typ.)
- Low power TTL compatibility: fan out of 2 driving 74L

Ordering Code:

Order Number	Package Number	Package Description
MM74C32N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Connection Diagram



Top View

Absolute Maximum Ratings (Note 1)

Voltage at Any Pin	−0.3V to V_{CC} + 0.3V
Operating Temperature Range	−55°C to +125°C
Storage Temperature Range	−65°C to +150°C
Power Dissipation (P_D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating V_{CC} Range	3.0V to 15V
Absolute Maximum V_{CC}	18V
Lead Temperature	
(Soldering, 10 seconds)	260°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics table provides conditions for actual device operation.

DC Electrical Characteristics

Min/Max limits apply across temperature range unless otherwise noted

Symbol	Parameter	Conditions	Min	Typ	Max	Units
CMOS TO CMOS						
$V_{IN(1)}$	Logical "1" Input Voltage	V_{CC} = 5.0V	3.5			V
		V_{CC} = 10V	8.0			
$V_{IN(0)}$	Logical "0" Input Voltage	V_{CC} = 5.0V			1.5	V
		V_{CC} = 10V			2.0	
$V_{OUT(1)}$	Logical "1" Output Voltage	V_{CC} = 5.0V, I_O = −10 µA	4.5			V
		V_{CC} = 10V, I_O = −10 µA	9.0			
$V_{OUT(0)}$	Logical "0" Output Voltage	V_{CC} = 5.0V, I_O = 10 µA			0.5	V
		V_{CC} = 10V, I_O = 10 µA			1.0	
$I_{IN(1)}$	Logical "1" Input Current	V_{CC} = 15V, V_{IN} = 15V		0.005	1.0	µA
$I_{IN(0)}$	Logical "0" Input Current	V_{CC} = 15V, V_{IN} = 0V	−1.0	−0.005		µA
I_{CC}	Supply Current	V_{CC} = 15V		0.05	15	µA
CMOS/LPTTL INTERFACE						
$V_{IN(1)}$	Logical "1" Input Voltage	V_{CC} = 4.75V	V_{CC} − 1.5			V
$V_{IN(0)}$	Logical "0" Input Voltage	V_{CC} = 4.75V			0.8	V
$V_{OUT(1)}$	Logical "1" Output Voltage	V_{CC} = 4.75V, I_O = −360 µA	2.4			V
$V_{OUT(0)}$	Logical "0" Output Voltage	V_{CC} = 4.75V, I_O = 360 µA			0.4	V
OUTPUT DRIVE (see Family Characteristics Data Sheet) T_A = 25°C (short circuit current)						
I_{SOURCE}	Output Source Current (P-Channel)	V_{CC} = 5.0V, V_{OUT} = 0V	−1.75	−3.3		mA
I_{SOURCE}	Output Source Current (P-Channel)	V_{CC} = 10V, V_{OUT} = 0V	−8.0	−15		mA
I_{SINK}	Output Sink Current (N-Channel)	V_{CC} = 5.0V, V_{OUT} = V_{CC}	1.75	3.6		mA
I_{SINK}	Output Sink Current (N-Channel)	V_{CC} = 10V, V_{OUT} = V_{CC}	8.0	16		mA

AC Electrical Characteristics (Note 2)

T_A = 25°C, C_L = 50 pF, unless otherwise specified

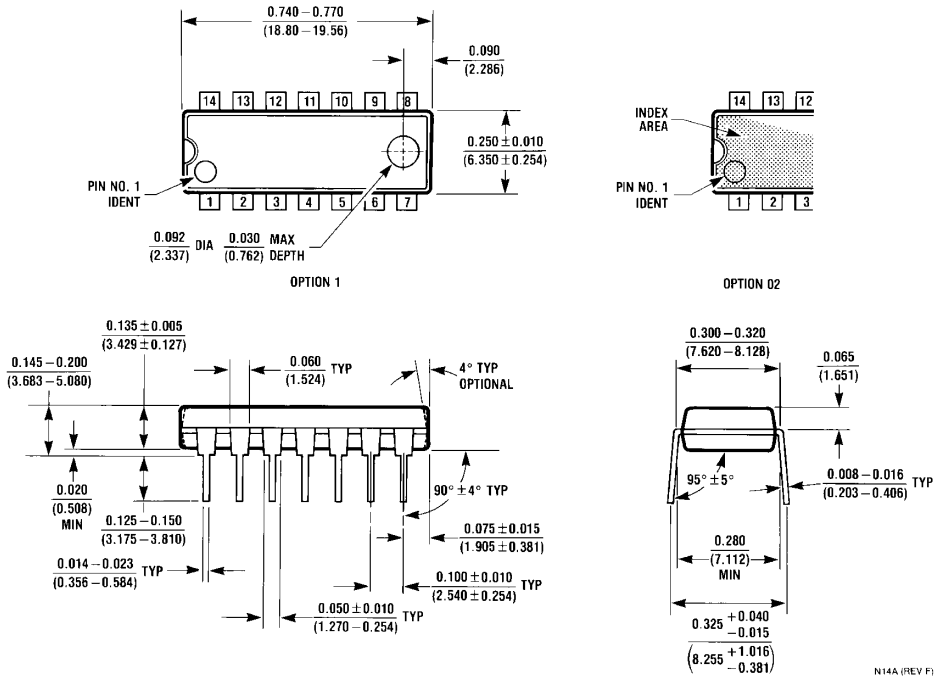
Symbol	Parameter	Conditions	Min	Typ	Max	Units
t_{pd}	Propagation Delay Time to	V_{CC} = 5.0V		80	150	ns
	Logical "1" or "0"	V_{CC} = 10V		35	70	ns
C_{IN}	Input Capacitance	Any Input (Note 3)		5		pF
C_{PD}	Power Dissipation Capacitance	Per Gate (Note 4)		15		pF

Note 2: AC Parameters are guaranteed by DC correlated testing.

Note 3: Capacitance is guaranteed by periodic testing.

Note 4: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation see Family Characteristics Application Note—AN-90.

Physical Dimensions inches (millimeters) unless otherwise noted



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Package Number N14A